

Symposium Transport in Graphene (SYTG)

jointly organized by
Semiconductor Physics Devision (HL), and
Dynamics and Statistical Physics Devision (DY)

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Overview of Invited Talks and Sessions
(lecture room BAR SCHÖ)

Invited Talks

SYTG 1.1	Tue	14:00–14:30	BAR SCHÖ	The nature of localization in graphene under quantum Hall conditions — ●JURGEN SMET
SYTG 1.2	Tue	14:30–15:00	BAR SCHÖ	Electronic Transport in Graphene Nanostructures — ●THOMAS IHN, CHRISTOPH STAMPFER, JOHANNES GÜTTINGER, FRANCOISE MOLITOR, STEPHAN SCHNEZ, ARNHILD JACOBSEN, KLAUS ENSSLIN
SYTG 1.3	Tue	15:00–15:30	BAR SCHÖ	Spins and valley-spins in graphene nanostructures — ●INANC ADAGIDELI
SYTG 1.4	Tue	15:30–16:00	BAR SCHÖ	Theory of ballistic transport in graphene — ●BJOERN TRAUZETTEL

Sessions

SYTG 1.1–1.4	Tue	14:00–16:00	BAR SCHÖ	Symposium: Transport in Graphene
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